

Technical Data Data Sheet N1216, Rev. B **Green Products**

306CMQ200 SCHOTTKY RECTIFIER

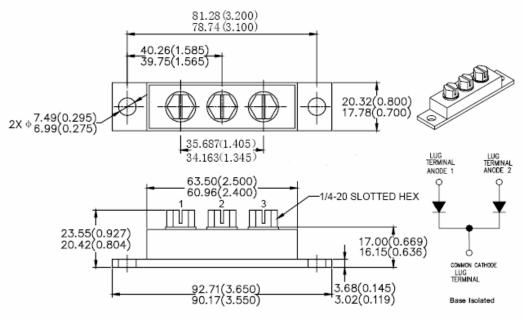
Applications:

- High current switching power supply Plating power supply Free-Wheeling diodes
- Reverse battery protection
 Converters
 UPS System
 Welding

Features:

- 175 ℃ T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm/Inches



Please Note: Anode 1 = Terminal 1; Anode 2 = Terminal 3; Common Cathode = Terminal 2 Suffix R Denotes for Reversed Polarity.

PRM4 (Isolated)

MARKING,MOLDING RESIN Marking for 306CMQ200, 1st row SS YYWWL, 2nd row 306CMQ200 Where YY is the manufacture year WW is the manufacture week code L is the wafer's Lot Number Molding resin Epoxy resin UL:94V-0

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Maximum Ratings:

Characteristics	Symbol	Condition	Max.		Units
Peak Inverse Voltage	V _{RWM}	-	200		V
Max. Average Forward	I _{F(AV)}	50% duty cycle $@T_c = 121^{\circ}C$,	150	per leg	A
Current		rectangular wave form	300	per device	
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	3840		A

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V _{F1}	@ 150A, Pulse, T _J = 25 °C	0.86	V
		@ 300A, Pulse, T _J = 25 °C	1.03	
	V_{F2}	@ 150A, Pulse, T _J = 125 °C	0.76	V
		@ 300A, Pulse, T _J = 125 °C	0.86	
Max. Reverse Current (per	I _{R1}	$@V_R = rated V_R T_J = 25 °C$	10	mA
leg) *	I _{R2}	$@V_R = rated V_R T_J = 125 \ ^\circ C$	90	mA
Max. Junction Capacitance	Ст	$@V_{R} = 5V, T_{C} = 25 \ ^{\circ}C$	3500	pF
(per leg)	0	f _{SIG} = 1MHz	8888	
Typical Series Inductance	Ls	Measured lead to lead 5 mm	7.0	nH
(per leg)	∟s	from package body	1.0	
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs
Insulation Voltage	V _{RMS}	-	1000	V

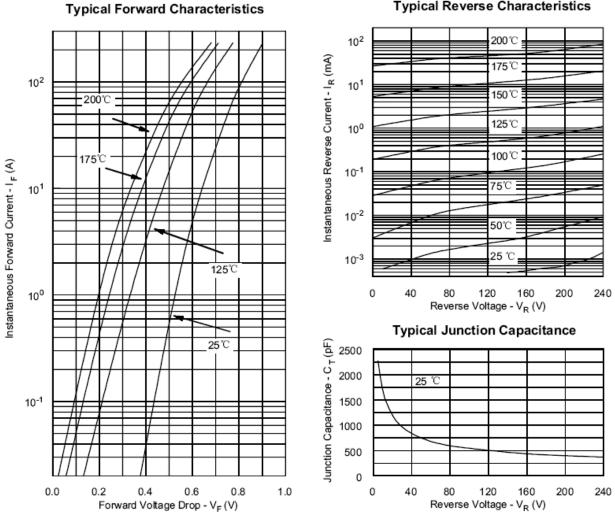
* Pulse Width < 300 μ s, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specifi	Units			
Max. Junction Temperature	TJ	-	-55 to	°C			
Max. Storage Temperature	T _{stg}	-	-55 to	°C			
Maximum Thermal Resistance Junction to Case (per leg)	$R_{ ext{ heta}JC}$	DC operation	0.50		°C/W		
Maximum Thermal Resistance Junction to Case (per package)	$R_{ ext{ heta}JC}$	DC operation	0.25		°C/W		
Typical Thermal Resistance, case to Heat Sink	$R_{ hetacs}$	Mounting surface, smooth and greased	0.10		°C/W		
Mounting Torque	Тм	-	Mounting Torque Terminal Torque	24(min) 35(max) 35(min) 46(max)	Kg-cm		
Approximate Weight	wt	-	79		g		
Case Style	PRM4 Isolated						



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Typical Reverse Characteristics

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